Ordering number : EN6197C

LB1927

Monolithic Digital IC For Office Automation Equipment 3-phase Brushless Motor Driver



http://onsemi.com

Overview

The LB1927 is a 3-phase brushless motor driver well suited for drum and paper feed motors in laser printers, plain-paper copiers and other office automation equipment. Direct PWM drive allows control with low power losses. Peripheral circuitry including speed control circuit and FG amplifier is integrated, thus allows drive circuit to be constructed with a single chip.

Features

- 3-phase bipolar drive (30V, 2.5A)
- Direct PWM drive technique
- Built-in diode for absorbing output lower-side kickback
- Speed discriminator and PLL speed control
- Speed lock detection output
- Built-in forward/reverse switching circuit
- Built-in protection circuitry includes current limiter, overheat protection, motor restraint protection, etc.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		30	V
Maximum output current	I _O max	T ≤ 500ms	2.5	Α
Allowable power dissipation 1	Pd max 1	Independent IC	3	W
Allowable power dissipation 2	Pd max 2	With an arbitrary large heat sink	20	W
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

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Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage range 1	v _{CC}		9.5 to 28	٧
Regulator voltage output current	I _{REG}		-30 to 0	mA
LD output current	I _{LD}		0 to 15	mA

Electrical Characteristics at Ta = 25°C, $V_{CC} = V_{M} = 24V$

Parameter	Symbol	Conditions		Ratings		Unit
raidilletei	Symbol	Conditions	min	typ	max	Offic
Power supply current 1	I _{CC} 1			23	30	mA
Power supply current 2	I _{CC} 2	In STOP mode		3.5	5.0	mA
Output						
Output saturation voltage 1	V _O sat1	$I_O = 1.0A$, V_O (SINK) $+V_O$ (SOURCE)		2.0	2.5	V
Output saturation voltage 2	V _O sat2	$I_O = 2.0A$, V_O (SINK) $+V_O$ (SOURCE)		2.6	3.2	V
Output leak current	l _O leak				100	μΑ
Lower-side diode forward voltage 1	V _D 1	ID = -1.0A		1.2	1.5	V
Lower-side diode forward voltage 2	V _D 2	ID = -2.0A		1.5	2.0	V
5V regulator voltage output						
Output voltage	V _{REG}	I _O = -5mA	4.65	5.00	5.35	V
Voltage fluctuation	ΔV _{REG} 1	V _{CC} = 9.5 to 28V		30	100	mV
Load fluctuation	∆V _{REG} 2	I _O = -5 to -20mA		20	100	mV
Hall amplifier			l-	l-		
Input bias current	I _{HB}		-2	-0.5		μΑ
Common mode input voltage range	VICM		1.5		V _{REG} -1.5	V
Hall input sensitivity			80			mVp-p
Hysteresis width	ΔV_{IN}		15	24	42	mV
Input voltage L→H	VSLH			12		mV
Input voltage H→L	VSHL			-12		mV
PWM oscillator						
Output High level voltage	V _{OH} (PWM)		2.5	2.8	3.1	V
Output Low level voltage	V _{OL} (PWM)		1.2	1.5	1.8	V
Oscillator frequency	F (PWM)	C = 3900pF		18		kHz
Amplitude	V (PWM)		1.05	1.30	1.55	Vp-p
CSD circuit	. (,	<u> </u>				- 19 19
Operating voltage	V _{OH} (CSD)		3.6	3.9	4.2	V
External capacitance charge	ICHG		-17	-12	-9	μΑ
current	10.10					μ
Operating time	T (CSD)	C = 10μF Design target value		3.3		s
Current limiter operation	•		•	•		
Limiter	VRF	V _{CC} -VM	0.45	0.5	0.55	V
Thermal shutdown operation		,	l-	l-		
Thermal shutdown operating temperature	TSD	Design target value (junction temperature)	150	180		°C
Hysteresis width	ΔTSD	Design target value (junction temperature)		50		°C
FG amplifier						
Input offset voltage	V _{IO} (FG)		-10		+10	mV
Input bias current	I _B (FG)		-1		+1	μА
Output High level voltage	V _{OH} (FG)	IFGO = -0.2mA	VREG-1.2	VREG-0.8	TI	V
Output Low level voltage	V _{OL} (FG)	IFGO = 0.2mA	***************************************	0.8	1.2	V
FG input sensitivity	VOL (I G)	GAIN 100 times	3	0.0	1.2	mV
Next-stage Schmitt comparator		Design target value	100	180	250	mV
width		3				
Operation frequency range					2	kHz
Open-loop gain		f (FG) = 2kHz	45	51		dB

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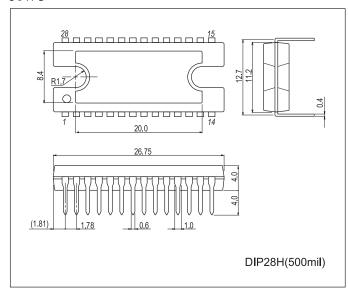
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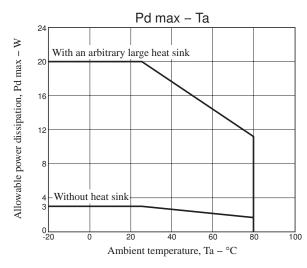
Parameter	Symbol	Conditions		Ratings		Unit
i didilietei	Symbol	Conditions	min	typ	max	Offic
Speed discriminator						
Output High level voltage	V _{OH} (D)	IDO = -0.1mA	VREG-1.0	VREG-0.7		V
Output Low level voltage	V _{OL} (D)	IDO = 0.1mA		0.8	1.1	V
Count number				512		
PLL output						
Output High level voltage	V _{OH} (P)	IPO = -0.1mA	VREG-1.8	VREG-1.5	VREG-1.2	V
Output Low level voltage	V _{OL} (P)	IPO = 0.1mA	1.2	1.5	1.8	٧
Lock detection						
Output Low level voltage	V _{OL} (LD)	ILD = 10mA		0.15	0.5	٧
Lock range				6.25		%
Integrator						
Input bias current	IB (INT)		-0.4		+0.4	μΑ
Output High level voltage	V _{OH} (INT)	I _{INTO} = -0.2mA	VREG-1.2	VREG-0.8		V
Output Low level voltage	V _{OL} (INT)	I _{INTO} = 0.2mA		0.8	1.2	V
Open-loop gain		f (INT) = 1kHZ	45	51		dB
Gain bandwidth product		Design target value		450		kHz
Reference voltage		Design target value	-5%	VREG/2	5%	V
Crystal oscillator		<u>.</u>				
Operating frequency range	fosc		3		10	MH:
Low level pin voltage	VoscL	I _{OSC} = -0.5mA		1.65		V
High level pin current	IOSCH	V _{OSC} = V _{OSC} L+0.3V		0.4		mA
Start/stop pin						
High level input voltage range	V _{IH} (S/S)		3.5		VREG	V
Low level input voltage range	V _{IL} (S/S)		0		1.5	V
Input open voltage	V _{IO} (S/S)		VREG-0.5		VREG	V
Hysteresis width	$\Delta V_{ extsf{IN}}$		0.35	0.50	0.65	V
High level input current	I _{IH} (S/S)	V (S/S) = VREG	-10	0	10	μΑ
Low level input current	I _{IL} (S/S)	V (S/S) = 0V	-280	-210		μΑ
Forward/reverse pin	•	•			<u> </u>	
High level input voltage range	V _{IH} (F/R)		3.5		VREG	V
Low level input voltage range	V _{IL} (F/R)		0		1.5	V
Input open voltage	V _{IO} (F/R)		VREG-0.5		VREG	V
Hysteresis width	ΔV _{IN}		0.35	0.50	0.65	V
High level input current	I _{IH} (F/R)	V (F/R) = VREG	-10	0	+10	μΑ
Low level input current	I _{IL} (F/R)	V (F/R) = 0V	-280	-210		μΑ

Package Dimensions

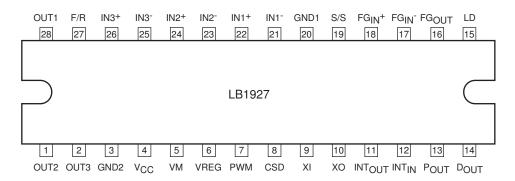
unit : mm (typ)

3147C





Pin Assignment



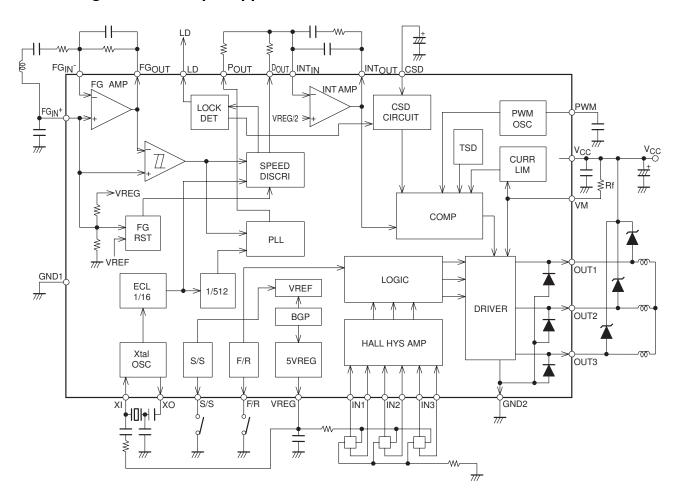
Top view

Relationship between crystal oscillator frequency f_{OSC} and FG frequency f_{FG} is as follows. f_{FG} (servo) = f_{OSC} / (ECL divide-by-16×count number) = f_{OSC} /8192

Truth Table

	Source		F/R = "L	,,	F	F/R = "H"		
	Sink	IN1	IN2	IN3	IN1	IN2	IN3	
1	OUT2→OUT1	Н	L	Н	L	Н	L	
2	OUT3→OUT1	Н	L	L	L	Н	Н	
3	OUT3→OUT2	Н	Н	L	L	L	Н	
4	OUT1→OUT2	L	Н	L	Н	L	Н	
5	OUT1→OUT3	L	Н	Н	Н	L	L	
6	OUT2→OUT3	L	L	Н	Н	Н	L	

Block Diagram and Sample Application Circuit



Pin Description

Pin Des	Pin name	Pin function	Equivalent circuit
28	OUT1	Motor drive output pins.	·
1	OUT2	Connect a Schottky diode between these outputs and V _{CC} .	<u>VCC</u> 300Ω VM
2	OUT3	The state of the s	30002 VM 5
3	GND2	Output ground pin.	
5	VM	Output block power supply and output current detection pin.	
	****	Connect a resistor (Rf) between this pin and V _{CC} to detect the	
		output current as a voltage.	1)(2)(28)
		The output current is limited according to the equation IOUT =	
		V _{RF} /R _f .	T
			$ \begin{array}{c} $
4	VCC	Power supply pin (except for output block).	
6	VREG	Regulated power supply output pin (5V output).	Vcc .
		Connect a capacitor (approx. 0.1µF) between this pin and ground to stabilize the output.	
		ground to stabilize the output.	
			├ . ★
			(6)
			
			*
			Ψ
			m m m
7	PWM	PWM frequency setting pin.	VREG
		Connect a capacitor between this pin and ground.	
		C = 3900pF results in a frequency of about 18kHz.	
			200Ω
			- $ -$
			2kΩ ξ
			mm mm mm
8	CSD	Lock protection circuit operation time setting pin.	VREG
		Connecting a capacitor of about 10µF between this pin and	
		ground results in a protection circuit operation time of about	
		3.3 seconds.	
			300Ω
			1kΩ
9	XI	Crystal oscillator pins.	VREG
10	XO	Connect to quartz oscillator to generate the reference clock.	
		When an external clock (of several MHz) is used, the clock	
		signal should be input via a resistor of about $5.1 \text{k}\Omega$ connected	
		in series with the XI pin. In this case, the XO pin must be left	
		open.	
			9
		1	

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Pin No.	from preced Pin name	Pin function	Equivalent circuit
11	INT _{OUT}	Integrator output pin (speed control pin).	VREG
	***************************************	integrater capacipin (opece control pin).	PWM comparator
12	INTIN	Integrator input pin.	VREG 300Ω 12
13	РОИТ	PLL output pin.	VREG 300Ω 13
14	Роит	Speed discriminator output pin. Acceleration : High, Deceleration : Low	VREG 300Ω 14
15	LD	Speed lock detection pin. When motor rotation is within lock range (±6.25%): Low Withstand voltage: 30V max.	VREG (15)

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Pin No.	Pin name	Pin function	Equivalent circuit
16	FG _{OUT}	FG amplifier output pin.	VREG 16 FG schmitt comparator
17 18	FG _{IN} ⁺	FG amplifier input pin. By connecting a capacitor (approx. 0.1μF) between FG _{IN} + and ground, the logic circuitry is reset.	VREG FG reset circuit 18 300Ω 17
19	S/S	Start/stop control pin. Start (Low): 0V to 1.5V Stop (High): 3.5V to VREG High when open. Hysteresis width: approx. 0.5V.	VREG ST 2k\Omega w 19
20	GND1	Ground pin (except for output block).	
22 21 24 23 26 25	IN1+ IN1- IN2+ IN2- IN3+ IN3-	Hall input pins. High when IN ⁺ > IN ⁻ , Low when IN ⁺ < IN ⁻ . Hall signal should have an amplitude of at least 100mVp-p (differential operation). When Hall signal noise is a problem, connect a capacitor between IN ⁺ and IN ⁻ .	21 (23 (25) 300Ω (22 (24 (26)) 1 mm m
27	F/R	Forward/reverse control pin. Forward (Low): 0V to 1.5V Reverse (High): 3.5V to VREG High when open. Hysteresis width: approx. 0.5V.	VREG Signature (27)

Description of the LB1927

1. Speed control circuit

The IC performs speed control through combined use of a speed discrimination circuit and PLL circuit. The speed control circuit counts FG cycles and outputs a deviation signal every 2FG cycles. The PLL circuit outputs a phase deviation signal every FG cycle.

The FG servo frequency is determined by the following equation. The motor rotation speed is set by the number of FG pulses and the crystal oscillator frequency.

fFG (servo) = fOSC/8192

fOSC: Crystal oscillator frequency

2. Output drive circuit

In order to reduce power loss at the output, the LB1927 uses the PWM drive technique. While ON, the output transistors are always saturated, and motor drive power is adjusted by varying the output ON duty ratio. Because output PWM switching is performed by the lower-side output transistor, a Schottky diode must be connected between OUT and V_{CC} . (If the reverse recovery time of the diode is too long, a feedthrough current will flow at the instant when the lower-side transistor goes ON.) An internal diode is provided between OUT and GND. If large output current causes a problem (waveform distortion during lower-side kickback, etc.), an external rectifying diode or Schottky diode should be connected.

The output diode is integrated only on the lower side.

3. Current limiting circuit

The current limiting circuit limits the peak current to the value I = VRF/Rf (VRF = 0.5V typ., Rf: current detector resistance). Current limiting is achieved by reducing the ON duty ratio of the output, which reduces the current.

4. Power save circuit

In order to reduce current drain in the STOP condition, the IC goes into power save mode. In this condition, bias current to most circuits is cut off, but the 5V regulator output remains active.

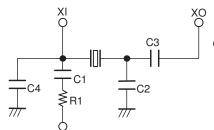
5. Reference clock

The reference clock for speed control can be input using one of the following two methods.

(1) Using a crystal oscillator

VREG

When a crystal is used for oscillation, connect the crystal, capacitors, and a resistor as shown in the figure below.



C1, R1: For stable oscillation

C3: For oscillator coupling

C2: For stabilization and to prevent oscillation at upper harmonic frequencies

C4 : Prevents oscillation at upper harmonic frequencies

(Reference values)

Oscillator frequency (MHz)	C1 (μF)	C2 (pF)	C3 (pF)	C4 (pF)	R1 (Ω)
3 to 5	0.1	15	47	10	330k
5 to 8	0.1	10	47	None	330k
8 to 10	0.1	10	22	None	330k

The circuit configuration and values are for reference only. The crystal oscillator's characteristics as well as the possibility of floating capacitance and noise due to layout factors must be taken into consideration when designing an actual application.

[Precautions for wiring layout design]

Since the crystal oscillator circuit operates at high frequencies, it is susceptible to the influence of floating capacitance from the circuit board. Wiring should be kept as short as possible and traces should be kept narrow. When designing the external circuitry, pay special attention to the wiring layout between the oscillator and C3 (C2), to minimize the influence of floating capacitance. The capacitor C4 is quite effective at reducing the negative resistance (gain) at high frequencies. However, care is required to avoid excessive reduction in the negative resistance at the fundamental frequency.

(2) External clock input (equivalent to crystal oscillator, several MHz)

When using an external signal source instead of a crystal oscillator, the clock signal should be input from the XI pin through a resistor of about $5.1k\Omega$ connected to the pin in series. The XO pin should be left open. Signal input level

Low: 0 to 0.8V High: 2.5 to 5.0V

6. Speed lock range

The speed clock range is $\pm 6.25\%$ of the rated speed. When the motor rotation is within the lock range, the LD pin becomes Low (open collector output). When the motor rotation goes out of the lock range, the ON duty ratio of the motor drive output is varied according to the amount of deviation to bring the rotation back into the lock range.

7. PWM frequency

The PWM frequency is determined by the capacitance connected to the PWM pin.

 $f PWM \approx 1/(14400 \times C)$

PWM frequency in the range 15 to 25kHz is desirable. The ground side of the connected capacitor must be connected to the GND1 pin with a lead that is as short as possible.

8. Hall input signal

The Hall input requires a signal with an amplitude of at least the hysteresis width (42mV max.). Taking possible noise influences into consideration, an amplitude of at least 100mV is desirable. If noise during output phase switching disrupts the output waveform, insert capacitors across the Hall signal inputs (between the + and - inputs), and position those capacitors as close as possible to the pins.

9. Forward/reverse switching

Forward/reverse switching of motor rotation is carried out with the F/R pin. If this is performed while the motor is running, the following points must be observed :

- Feedthrough current during switching is handled by proper circuit design. However, the V_{CC} voltage rise during switching (caused by momentary return of motor current to power supply) must not exceed the rated voltage (30V). If problems occur, the capacitance between V_{CC} and GND must be increased.
- If the motor current after switching exceeds the current limiter value, the lower-side transistors go OFF but the upper-side transistors go into the short brake state, which causes a current flow. The magnitude of the current is determined by the motor counterelectromotive voltage and the coil resistance. This current may not exceed the rated current (2.5A). (Forward/reverse switching at high speed therefore is not safe.)

10. Motor restraint protection circuit

To protect the IC and the motor itself when rotation is inhibited, a restraint protection circuit is provided. If the LD output is High (unlocked) for a certain interval in the start condition, the lower-side transistors are turned off. The length of the interval is determined by the capacitance at the CSD pin. A capacitance of $10\mu F$ results in a set interval of about 3.3 seconds. (Tolerance approx. $\pm 30\%$)

Set interval (s)
$$\approx 0.33 \times C (\mu F)$$

If the capacitor arrangement is subject to leak current, possible adverse effects such as setting time tolerances must be taken into consideration.

When the restraint protection circuit has been activated, the condition can only be canceled by setting the system to the stop condition or by turning the power off and on again (in the stop condition). When wishing not to use the restraint protection circuit, connect the CSD pin to ground.

If the stop time when releasing the restraint protection is short, the capacitor charge will not be fully dissipated. This in turn will cause a shorter restraint protection activation time after the motor has been restarted. The stop time should therefore be designed to be sufficiently long, using the equation shown below (also when restarting in the motor start transient state).

Stop time (ms) $\geq 15 \times C (\mu F)$

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11. Power supply stabilization

Because this IC provides a high output current and uses a switching drive technique, power supply line fluctuations can occur easily. Therefore, a capacitor of sufficient capacitance (several ten μF or higher) must be connected between the V_{CC} pin and ground to assure stable operation. The ground connection of this capacitor must be connected to the GND2 pin, which is the power block ground, at a point as close as possible to the IC. If, due to problems associated with the heat sink, the (electrolytic) capacitor cannot be connected near the this pin, a ceramic capacitor of about $0.1\mu F$ must be connected near the pin.

Since the likelihood of power line fluctuation increases if diodes are inserted in the power supply lines to prevent destruction of the IC if power is connected with reverse polarity, a larger capacitance will be required.

12. VREG stabilization

A capacitor (about $0.1\mu F$) must be connected to the VREG pin (the 5V regulator output), which functions as the control circuit power supply, for stabilization. The ground side of this capacitor must be connected to the GND1 pin with a lead that is as short as possible.

13. Integrating amplifier related component values

The external components used in the integrating amplifier must be located as close as possible to the IC to minimize the circuit's susceptibility to noise. These components must be located as far as possible from the motor.

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